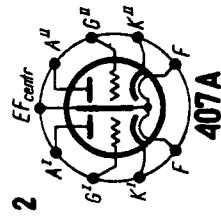
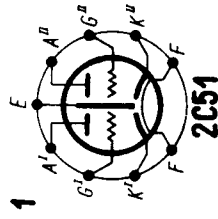


T.	int	Tes	SER	int	U _f	I _f	Cl.	U _a		U _g		I _a	S	R _j	μ	R _k	R _o	P _o	h
								V	A	V	V								
2 C 51	1	6,3	0,3	{ A 1	130	-1,5	7,6	5,4	6,5	35	200								
6 CC 42	1	6,3	0,35	{ A 1	150	-2	8,2	5,5	6,5	35	240								
18 C 51 ¹⁾	1	18	0,1	{ AB	300		(4,9 ÷ 6,3) × 2				800	27	1	10					
407 A ¹⁾	2	20/40	0,1/0,05		300		maximum (I _k = 18 mA; P _o = 1,5 W; f = 800 MHz; U _{flk} = 90 V)												



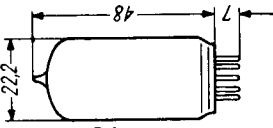
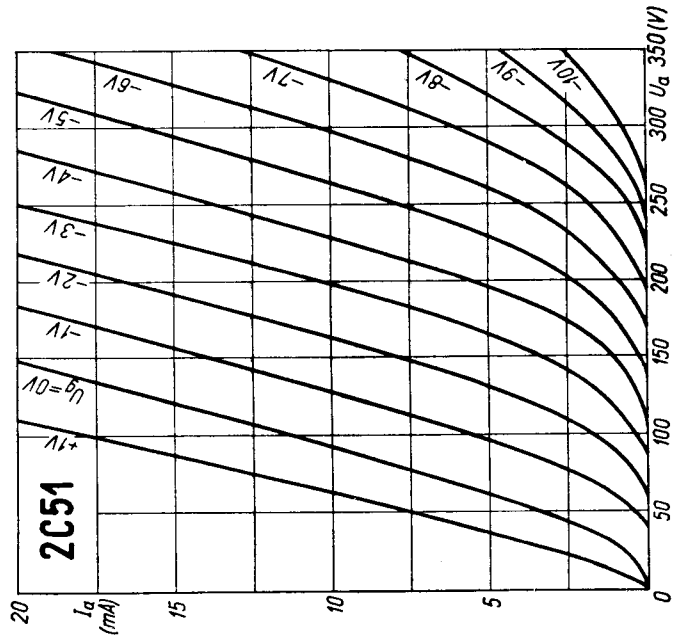
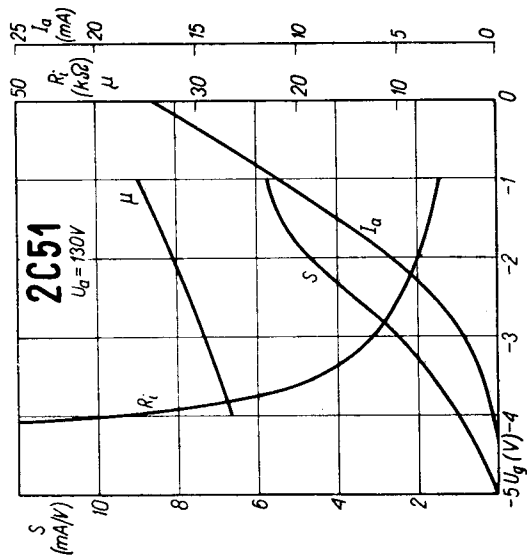
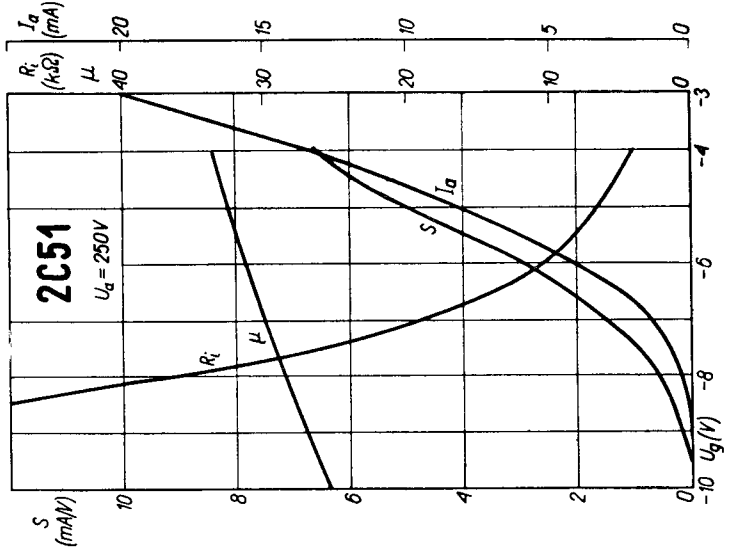
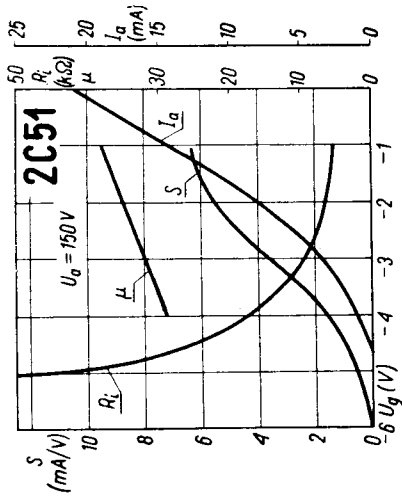
T.	C _{g/k}	C _{o/k}	C _{g/a}		C _{a/a} ^{I,II}
			pF	pF	
2 C 51	I-II triod.	2,2	1	1,3	0,05 ÷ 0,1
2 C 51 L					
407 A					
5670					
6 CC 42	I-II triod.	2,2	0,4	1,6	0,15
6 H 3 II					
	I-II triod.	2,8	1,45	1,3	0,04 ÷ 0,15

Equivalents

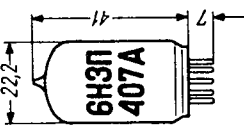
CK 5670 ²⁾	Ray = 6 CC 42	396 A	WE = 2 C 51
CK 5670 WA ³⁾	Ray = 6 CC 42	5670 ²⁾	amer = 6 CC 42
GL 5670 ²⁾	GE = 6 CC 42	5670 WA ³⁾	amer = 6 CC 42
2 C 51 L ¹⁾	SER = 2 C 51	6385	amer = 6 CC 42
6 H 3 II	CCCP = 6 CC 42		

¹⁾ vide * 4, a, b, c = 10000, d, e, f, g (U_f = 6,3 (18; 20/40) V ± 5%)

²⁾ vide * 4, a, b, c = 10000, f, g (U_f = 6,3 V ± 10%)



**2C51
6CC42
18C51
5670**



**6H3П
407A**

